

ELITE SEMICONDUCTOR PRODUCTS, INC.

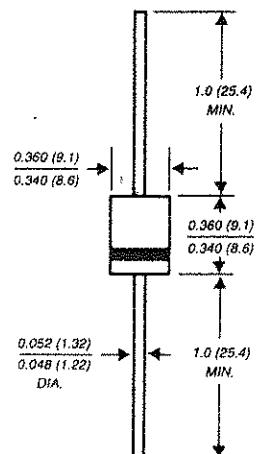
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GI750 THRU GI758

HIGH CURRENT PLASTIC RECTIFIER

Reverse Voltage - 50 to 800 Volts **Forward Current - 6.0 Amperes**

Case style P600



Dimensions are in inches and (millimeters)

FEATURES

- ♦ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
 - ♦ High forward current capability
 - ♦ Diffused junction
 - ♦ Construction utilizes void-free molded plastic technique
 - ♦ High surge current capability
 - ♦ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length,
5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: Void-free molded plastic body

Terminals: Plated axial leads, solderable per MIL-STD-750,
Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.07 ounce, 2.1 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	GI750	GI751	GI752	GI754	GI756	GI758	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	Volts
Maximum non-repetitive peak reverse voltage	V _{RSM}	60	120	240	480	720	1200	Volts
Maximum average forward rectified current at TA=60°C, P.C.B. mounting (FIG. 1) TL=60°C, 0.125" (3.18mm) lead length (FIG. 2)	I _(AV)				6.0			Amps
					22.0			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}			400.0				Amps
Maximum instantaneous forward voltage at 6.0A 100A	V _F			0.90		0.95		Volts
				1.25		1.30		
Maximum DC reverse current at rated DC blocking voltage	I _R			5.0				µA mA
TA=25°C TA=100°C				1.0				
Typical junction capacitance (NOTE 1)	C _J			150.0				pF
Typical reverse recovery time (NOTE 2)	t _{rr}			2.5				µs
Typical thermal resistance (NOTE 3)	R _{θJA} R _{θJL}			20.0				°C/W
				4.0				
Operating junction and storage temperature range	T _J , T _{STG}			-50 to +150				°C

NOTES:

- (1) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
 (2) Reverse recovery test conditions; $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$
 (3) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length,
 P.C.B. mounted with $1.1 \times 1.1"$ (30 x 30mm) copper pads